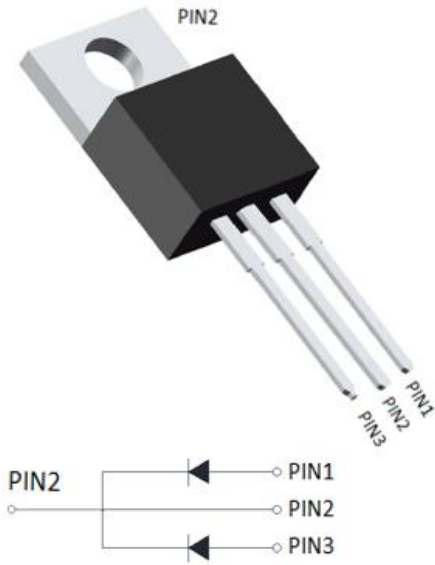


Schottky Diodes



Features

- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-220AB
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■Maximum Ratings ($T_a=25^\circ\text{C}$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR10200CT
Device marking code			MBR10200CT
Repetitive Peak Reverse Voltage	VRRM	V	200
Average Rectified Output Current @60Hz sine wave, R-load, $T_a=25^\circ\text{C}$	IO	A	10
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, $T_a=25^\circ\text{C}$	IFSM	A	120
Current Squared Time @ $1\text{ms} \leq t \leq 8.3\text{ms}$ $T_j=25^\circ\text{C}$	I^2t	A^2s	41
Storage Temperature	T_{stg}	$^\circ\text{C}$	-55 ~ +175
Junction Temperature	T_j	$^\circ\text{C}$	-55 ~ +175

■Electrical Characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBR10200CT
Maximum instantaneous forward voltage drop per diode	VFM	V	$I_{\text{FM}}=5.0\text{A}$	0.90
Maximum DC reverse current at rated DC blocking voltage per diode	I _{RRM1}	mA	$V_{\text{RM}}=V_{\text{RRM}}$ $T_a=25^\circ\text{C}$	0.1
	I _{RRM2}		$V_{\text{RM}}=V_{\text{RRM}}$ $T_a=100^\circ\text{C}$	20

Note1:Pulse test:300uS pulse width,1% duty cycle

Note2:Pulse test:pulse width 40mS



MBR10200CT-B1-W5094HF

■ Thermal Characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MBR10200CT
Thermal Resistance	Between junction and case	$R_{\theta J-c}$	$^\circ\text{C/W}$	2.0

■ Ordering Information (Example)

PREFERRED P/N	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBR10200CT	Approximate 1.9	50	1000	5000	Tube

■ Characteristics (Typical)

FIG1: $I_o - T_c$ Curve

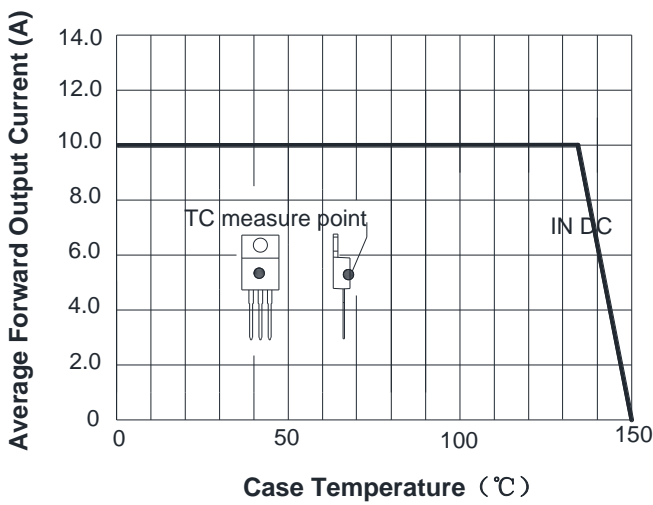


FIG2: Surge Forward Current Capability

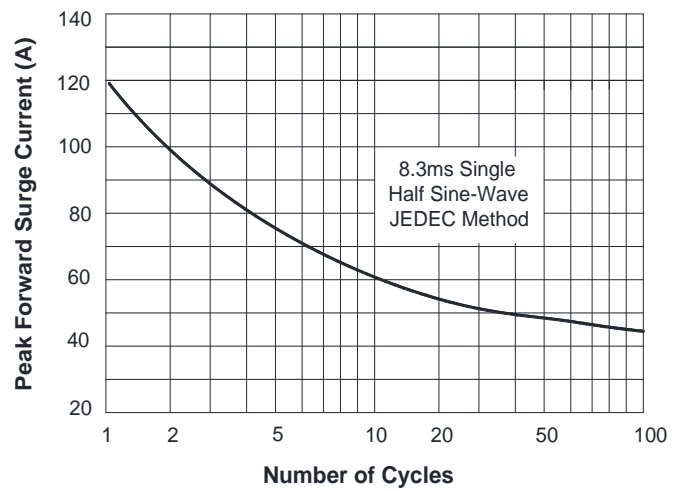


FIG3: Forward Voltage

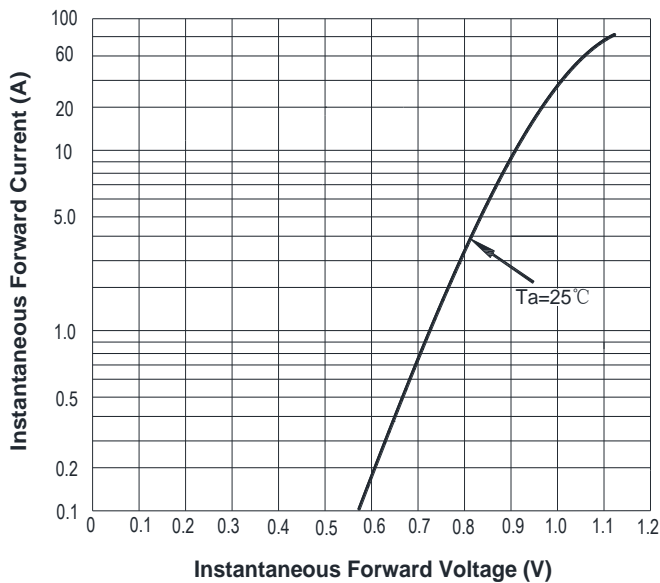
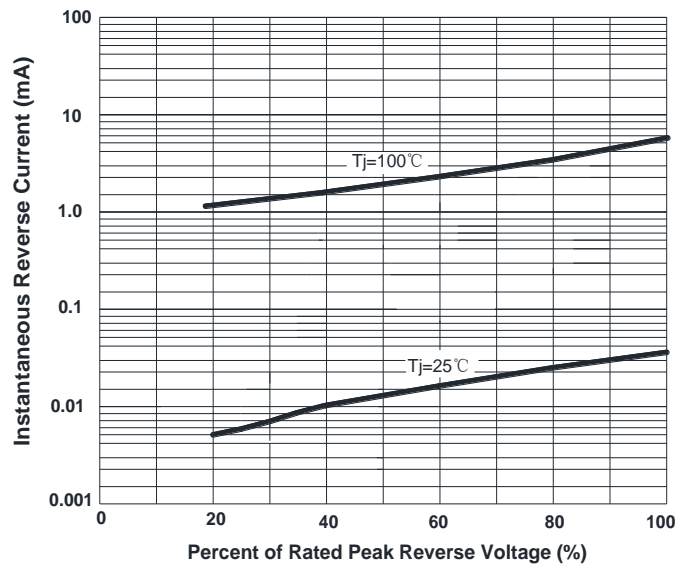


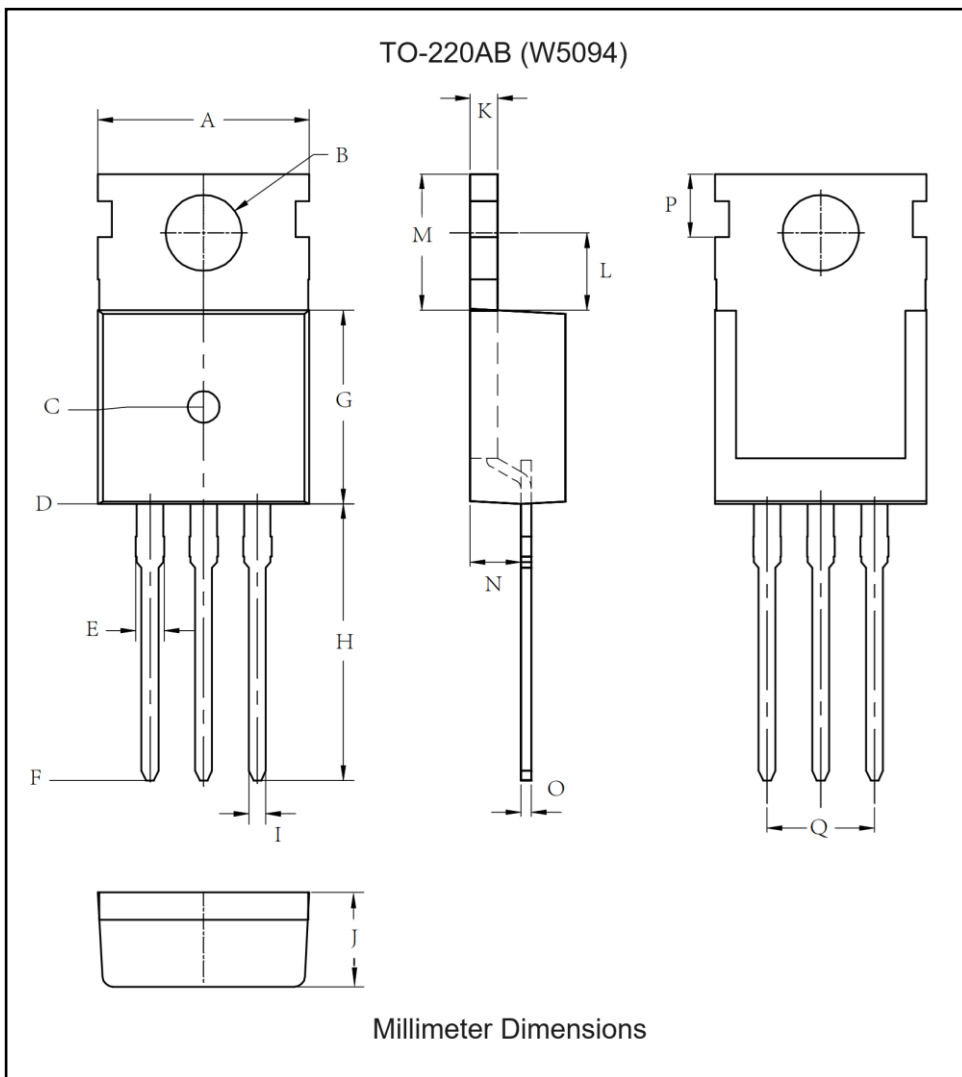
FIG.4: Typical Reverse Characteristics





MBR10200CT-B1-W5094HF

■Outline Dimensions



TO-220AB		
Dim	Min	Max
A	9.9	10.1
B	TYP 3.6	
C	8.06	8.46
D	12.67	13.07
E	1.28	1.42
F	25.7	26.3
G	9	9.4
H	12.93	13.33
I	TYP 0.8	
J	4.3	4.7
K	1.285	1.315
L	3.47	3.87
M	6.27	6.67
N	2.2	2.6
O	0.485	0.515
P	2.8	3.2
Q	TYP 5.08	



MBR10200CT-B1-W5094HF

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